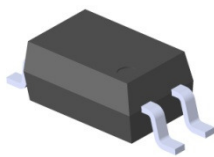
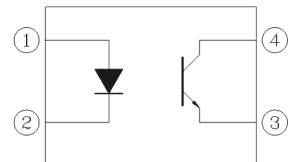


4 PIN SSOP PHOTOTRANSISTOR PHOTOCOUPLER EL3H7-G Series



Schematic



Features:

- Halogens free
(Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)
- Current transfer ratio
(CTR: 50~600% at IF =5mA, VCE =5V)
(CTR: 40~320% at IF =10mA, VCE =5V)
- High isolation voltage between input and output (Viso=3750 V rms)
- Compact 4 Pin SSOP with a 2.0 mm profile
- Compliance with EU REACH
- Pb free and RoHS compliant.
- UL and cUL approved(No. E214129)
- VDE approved (No. 132249)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

Pin Configuration

1. Anode
2. Cathode
3. Emitter
4. Collector

Description

The EL3H7-G series devices consist of an infrared emitting diode, optically coupled to a phototransistor detector encapsulated with green compound.

They are packaged in a 4-pin small outline SMD package.

Applications

- DC-DC Converters
- Programmable controllers
- Telecommunication equipments
- Signal transmission between circuits of different potentials and impedances

Absolute Maximum Ratings (Ta=25°C)

	Parameter	Symbol	Rating	Unit
Input	Forward current	I_F	50	mA
	Peak forward current (1us, pulse)	I_{FP}	1	A
	Reverse voltage	V_R	6	V
	Power dissipation	P_D	70	mW
	Derating factor (above $T_a = 90^\circ\text{C}$)		2.0	mW/°C
Output	Power dissipation	P_C	150	mW
	Derating factor (above $T_a = 70^\circ\text{C}$)		3.1	mW/°C
	Collector current	I_C	50	mA
	Collector-Emitter voltage	V_{CEO}	80	V
	Emitter-Collector voltage	V_{ECO}	7	V
Total Power Dissipation		P_{TOT}	200	mW
Isolation Voltage*1		V_{ISO}	3750	Vrms
Operating temperature		T_{OPR}	-55 ~ +110	°C
Storage temperature		T_{STG}	-55 ~ +125	°C
Soldering Temperature*2		T_{SOL}	260	°C

Notes:

*1 AC for 1 minute, R.H.= 40 ~ 60% R.H. In this test, pins 1, 2 are shorted together, and pins 3, 4 are shorted together.

*2 For 10 seconds

Electro-Optical Characteristics (Ta=25°C unless specified otherwise)

Input

Parameter	Symbol	Min.	Typ.	Max.	Unit	Condition
Forward voltage	V_F	-	1.2	1.4	V	$I_F = 20\text{mA}$
Reverse current	I_R	-	-	10	μA	$V_R = 4\text{V}$
Input capacitance	C_{in}	-	30	250	pF	$V = 0, f = 1\text{kHz}$

Output

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Collector-Emitter dark current	I_{CEO}	-	-	100	nA	$V_{CE} = 20\text{V}, I_F = 0\text{mA}$
Collector-Emitter breakdown voltage	BV_{CEO}	80	-	-	V	$I_C = 0.1\text{mA}$
Emitter-Collector breakdown voltage	BV_{ECO}	7	-	-	V	$I_E = 0.1\text{mA}$

Transfer Characteristics (Ta=25°C unless specified otherwise)

Parameter	Symbol	Min	Typ.	Max.	Unit	Condition
Current Transfer ratio	EL3H7	50	-	600	%	$I_F = 5\text{mA}, V_{CE} = 5\text{V}$
	EL3H7A	80	-	160		
	EL3H7B	130	-	260		
	EL3H7C	200	-	400		
	EL3H7D	300	-	600		
	EL3H7E	100	-	200		
	EL3H7F	150	-	300		
	EL3H7H	40	-	80		
	EL3H7I	63	-	125		
	EL3H7J	100	-	200		$I_F = 10\text{mA}, V_{CE} = 5\text{V}$
	EL3H7K	160	-	320		
Collector-Emitter saturation voltage	$V_{CE(sat)}$	-	0.1	0.2	V	$I_F = 10\text{mA}, I_C = 1\text{mA}$
Isolation resistance	R_{IO}	5×10^{10}	-	-	Ω	$V_{IO} = 500\text{Vdc}, 40 \sim 60\% \text{ R.H.}$
Floating capacitance	C_{IO}	-	0.3	1.0	pF	$V_{IO} = 0, f = 1\text{MHz}$
Rise time	t_r	-	5	18	μs	$V_{CE} = 2\text{V}, I_C = 2\text{mA}, R_L = 100\Omega$
Fall time	t_f	-	3	18	μs	

* Typical values at $T_a = 25^\circ\text{C}$

Typical Electro-Optical Characteristics Curves

Figure 1. Forward Current vs Forward Voltage

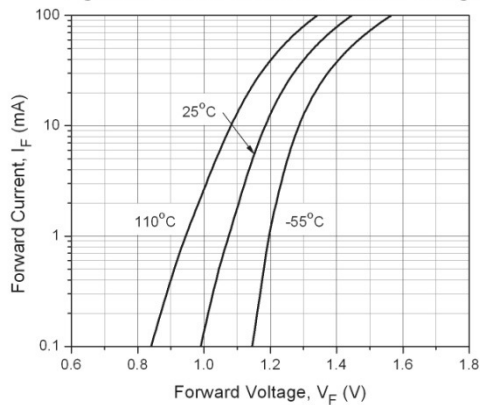


Figure 2. Normalized Collector Current vs Forward Current

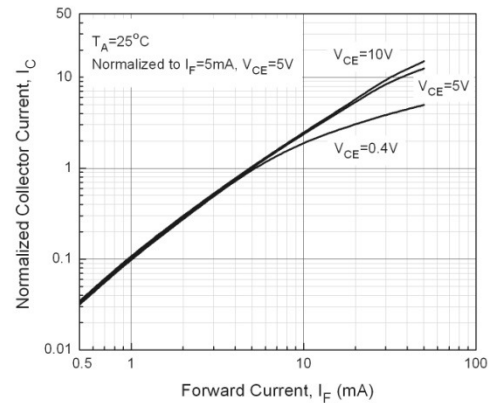


Figure 3. Normalized Current Transfer Ratio vs Forward Current

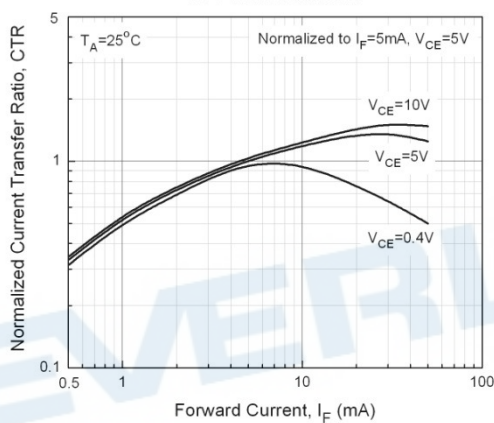


Figure 4. Normalized Collector Current vs Ambient Temperature

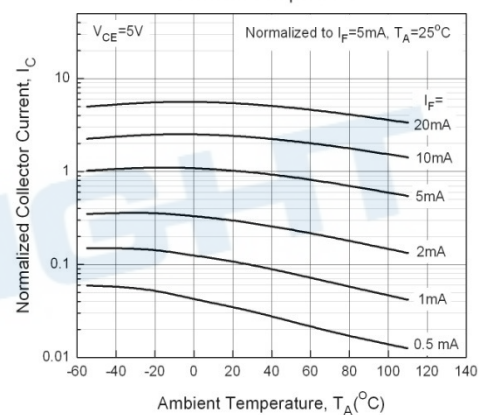


Figure 5. Normalized Current Transfer Ratio vs Ambient Temperature

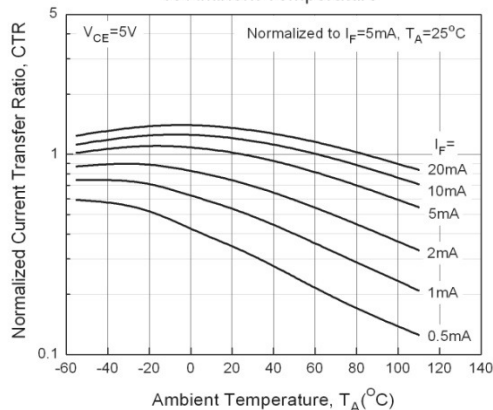


Figure 6. Collector Current vs Collector-Emitter Voltage

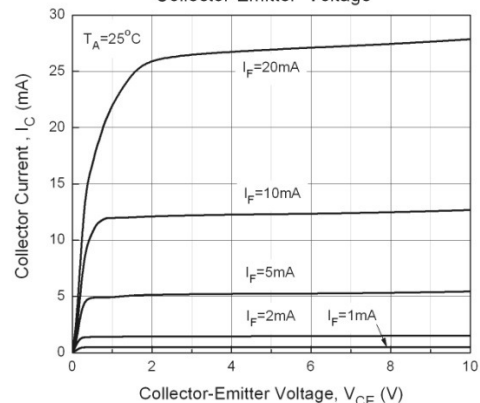


Figure 7. Collector Current vs Collector-Emitter Voltage

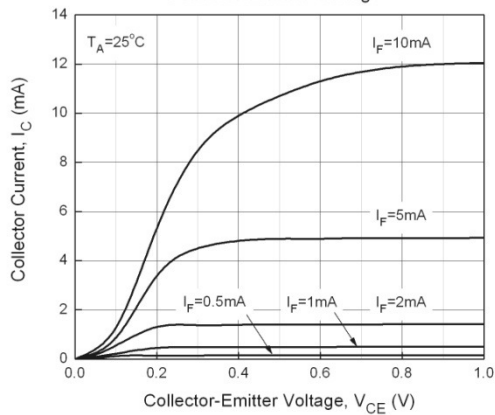


Figure 8. Collector Dark Current vs Ambient Temperature

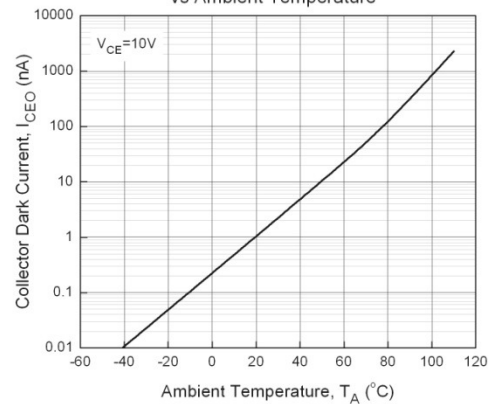


Figure 9. Collector-Emitter Saturation Voltage vs Ambient Temperature

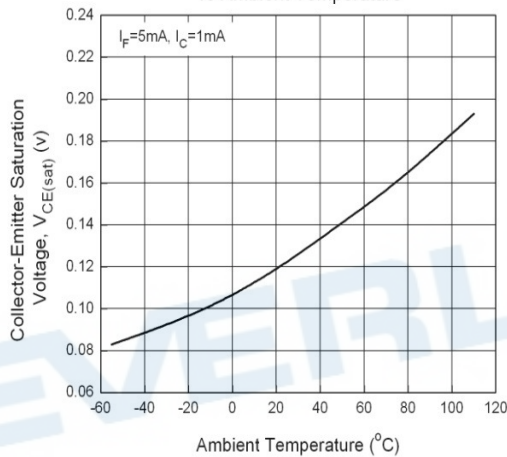


Figure 10. Switching Time vs Load Resistance

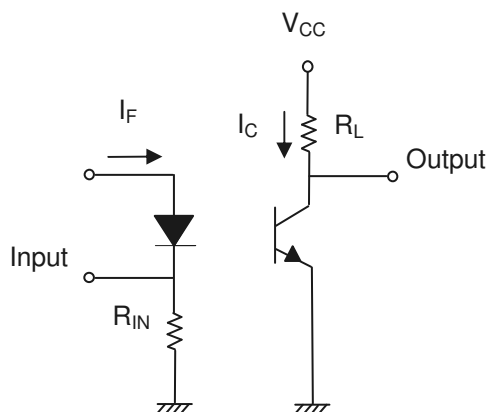
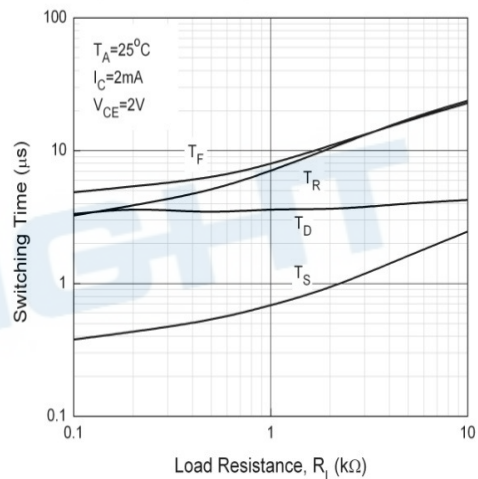


Figure 11. Switching Time Test Circuit & Waveforms

Order Information

Part Number

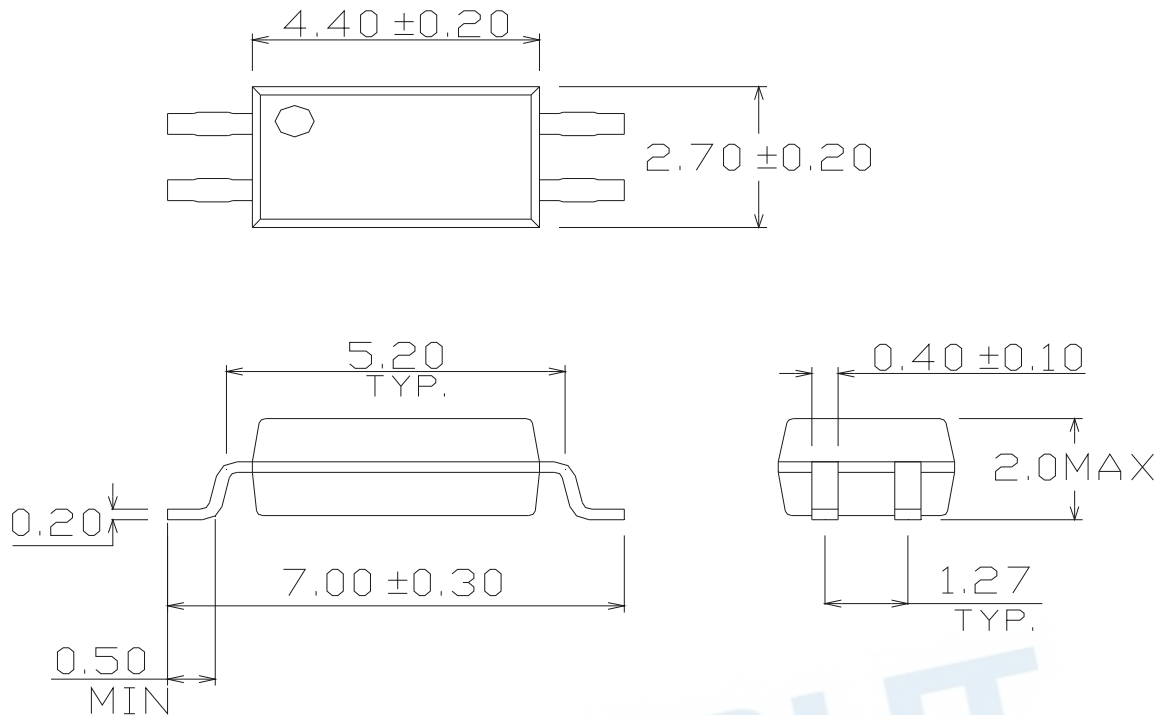
EL3H7(X)(Y)-VG

Note

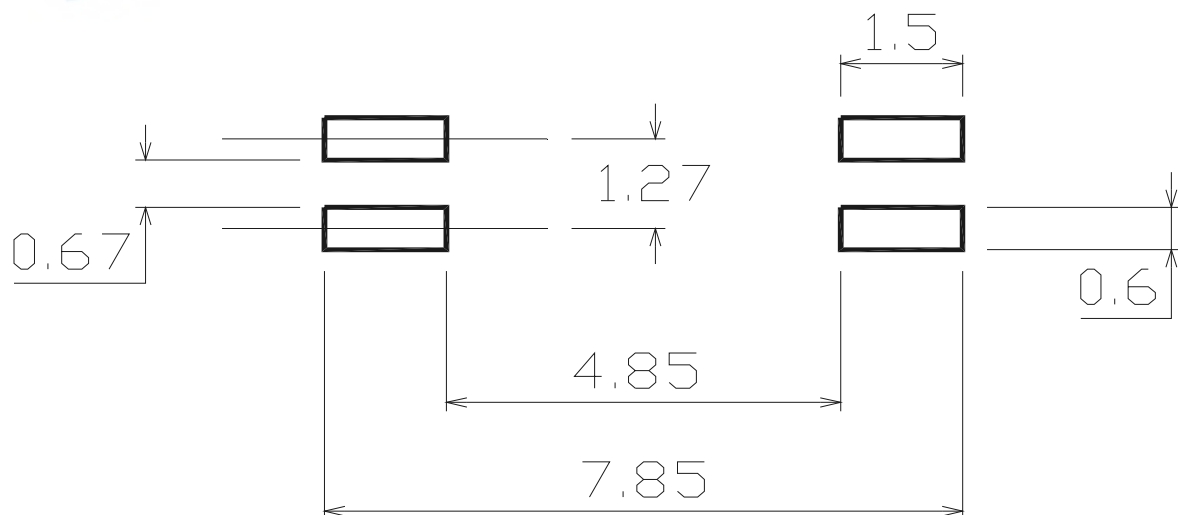
- X = CTR Rank (A, B, C, D, E, F, H, I, J, K or none)
Y = Tape and reel option (TA, TB, EA, EB or none)
V = VDE (optional)
G = Halogens free

Option	Description	Packing quantity
None	Standard SMD option	150 units per tube
-V	Standard SMD option + VDE	150 units per tube
(TA)	TA Tape & reel option	5000 units per reel
(TB)	TB Tape & reel option	5000 units per reel
(TA)-V	TA Tape & reel option + VDE	5000 units per reel
(TB)-V	TB Tape & reel option + VDE	5000 units per reel
(EA)	TA Tape & reel option	1000 units per reel
(EB)	TB Tape & reel option	1000 units per reel
(EA)-V	TA Tape & reel option + VDE	1000 units per reel
(EB)-V	TB Tape & reel option + VDE	1000 units per reel

Package Dimension (Dimensions in mm)



Recommended pad layout for surface mount leadform



Device Marking



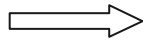
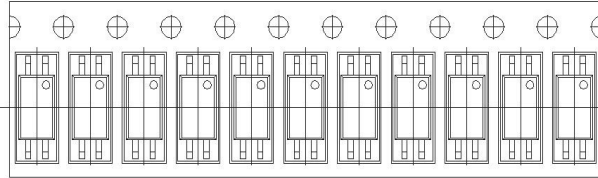
Notes

EL	denotes Everlight
3H7	denotes Device Number
R	denotes CTR Rank (A, B, C, D, E, F, H, I, J, K or none)
Y	denotes 1 digit Year code
WW	denotes 2 digit Week code
V	denotes VDE (optional)

EVERLIGHT

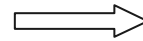
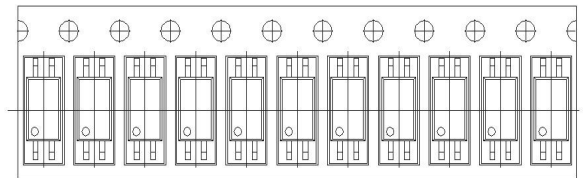
Tape & Reel Packing Specifications

Option TA



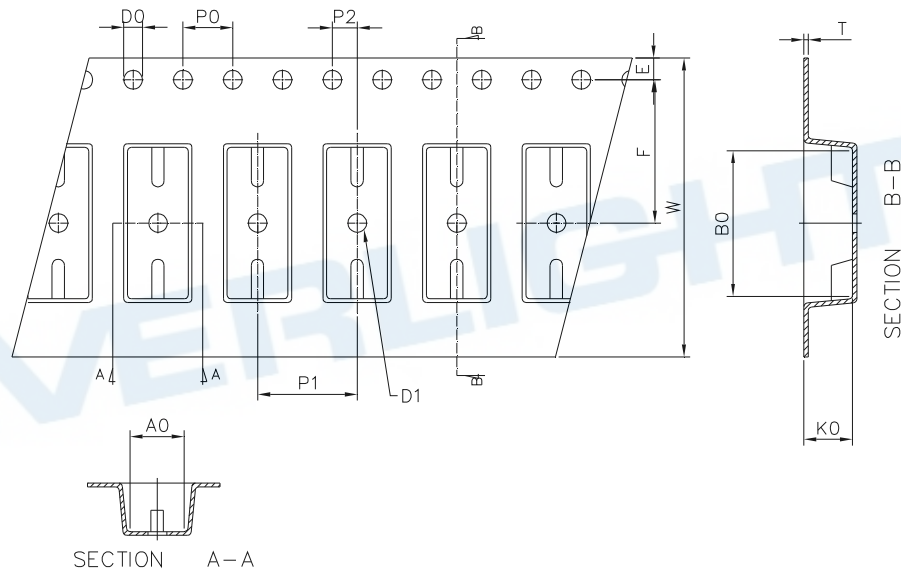
Direction of feed from reel

Option TB



Direction of feed from reel

Tape dimensions

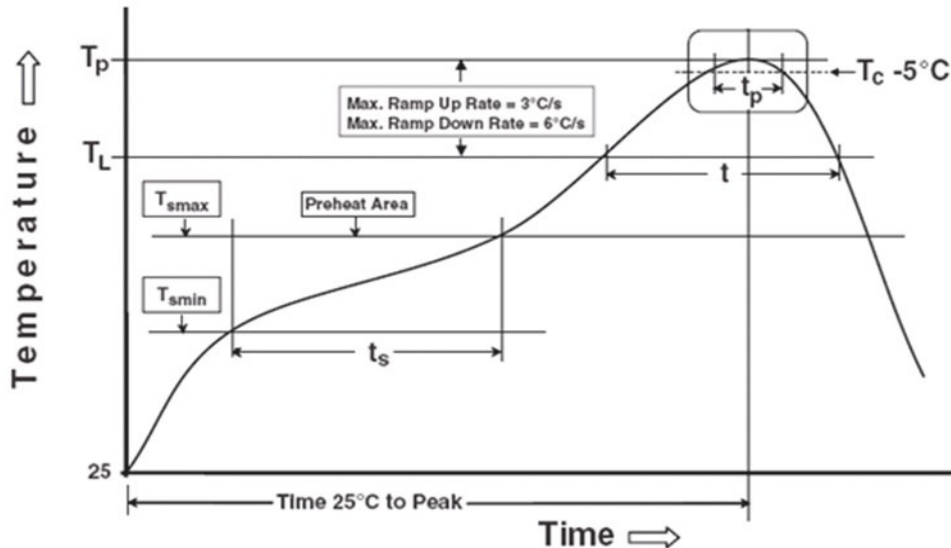


Dimension No.	A0	B0	D0	D1	E	F
Dimension (mm)	3.00 ± 0.10	7.45 ± 0.10	1.50 + 0.1/-0	1.50 ± 0.10	1.75 ± 0.10	5.50 ± 0.10
Dimension No.	P0	P1	P2	t	W	K0
Dimension (mm)	4.00 ± 0.15	4.00 ± 0.10	2.00 ± 0.10	0.30 ± 0.05	12.1 ± 0.2	2.45 ± 0.1

Precautions for Use

1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note:

Reference: IPC/JEDEC J-STD-020D

Preheat

Temperature min (T_{smin})	150 °C
Temperature max (T_{smax})	200 °C
Time (T_{smin} to T_{smax}) (t_s)	60-120 seconds
Average ramp-up rate (T_{smax} to T_p)	3 °C/second max

Other

Liquidus Temperature (T_L)	217 °C
Time above Liquidus Temperature (t_L)	60-100 sec
Peak Temperature (T_p)	260 °C
Time within 5 °C of Actual Peak Temperature: $T_p - 5^\circ\text{C}$	30 s
Ramp- Down Rate from Peak Temperature	6°C /second max.
Time 25°C to peak temperature	8 minutes max.
Reflow times	3 times

DISCLAIMER

1. Above specification may be changed without notice. EVERLIGHT will reserve authority on material change for above specification.
2. When using this product, please observe the absolute maximum ratings and the instructions for using outlined in these specification sheets. EVERLIGHT assumes no responsibility for any damage resulting from use of the product which does not comply with the absolute maximum ratings and the instructions included in these specification sheets.
3. These specification sheets include materials protected under copyright of EVERLIGHT corporation. Please don't reproduce or cause anyone to reproduce them without EVERLIGHT's consent.

EVERLIGHT